## **TOSHIBA**

TOSHIBA BI-DIRECTIONAL TRIODE THYRISTOR SILICON PLANAR TYPE

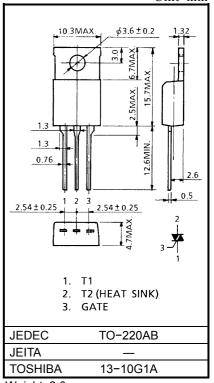
# SM16G45,SM16J45,SM16G45A,SM16J45A

AC POWER CONTROL APPLICATIONS

- Repetitive Peak Off-State Voltage : V<sub>DRM</sub> = 400, 600V
- R.M.S On–State Current
- : I<sub>T</sub> (RMS) = 16A
- High Commutating (dv / dt)

### MAXIMUM RATINGS

CHARACTER	RISTIC	SYMBOL	RATING	UNIT	
Repetitive Peak Off-State Voltage	SM16G45 SM16G45A	VDRM	400	V	
	SM16J45 SM16J45A	V DRM	600	v	
R.M.S On-State Curre (Full Sine Waveform Te		I <sub>T (RMS)</sub>	16	А	
Peak One Cycle Surge	On-State	<b>I</b>	150 (50Hz)	А	
Current (Non-Repetitive)		ITSM	165 (60Hz)	A	
I <sup>2</sup> t Limit Value		l <sup>2</sup> t	112.5	A <sup>2</sup> s	
Peak Gate Power Diss	ipation	P <sub>GM</sub>	5	W	
Average Gate Power D	vissipation	P <sub>G (AV)</sub>	0.5	W	
Peak Gate Voltage		V <sub>GM</sub>	10	V	
Peak Gate Current		I <sub>GM</sub>	2	А	
Junction Temperature		Tj	-40~125	°C	
Storage Temperature F	Range	T <sub>stg</sub>	-40~125	°C	



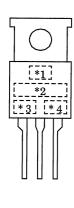


Unit: mm

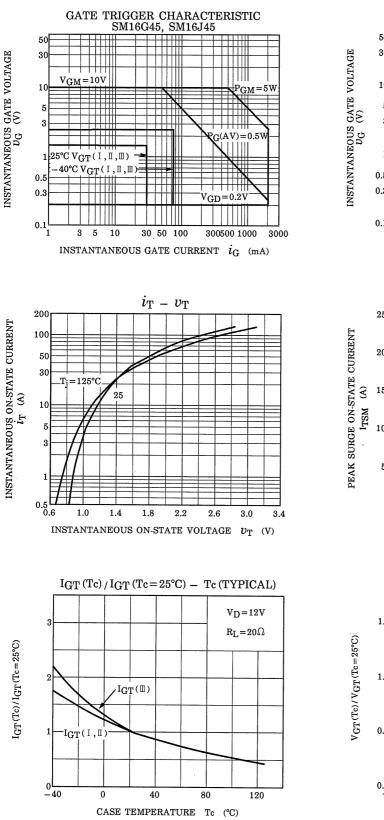
## ELECTRICAL CHARACTERISTICS (Ta = 25°C)

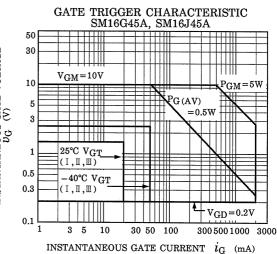
CHARACTERISTIC		SYMBOL	TEST CONDITION		MIN	TYP.	MAX	UNIT		
Repetitive Peak Off-State Current			I <sub>DRM</sub>	V <sub>DRM</sub> = Rated		_	—	20	μA	
Gate Trigger Voltage		- V <sub>GT</sub>	V <sub>D</sub> = 12V,	T2 (+) , Gate (+)		—	1.5	v		
				T2 (+) , Gate (−)	_	_	1.5			
		Ш	$R_L = 20$	R <sub>L</sub> = 20Ω	= 20Ω T2 (-) , Gate (-)		—	1.5		
		IV			T2 (-) , Gate (-)		—	—		
Gate Trigger Current		SM16G45				T2 (+) , Gate (+)	_	—	30	-
						T2 (+) , Gate (−)	_	—	30	
	SM16	SM16J45	Ш			T2 (−) , Gate (−)	_	—	30	
					V <sub>D</sub> = 12V,	T2 (-) , Gate (+)	_	—	—	mA
		SM16G45A	Ι	IGT	R <sub>L</sub> = 20Ω	T2 (+) , Gate (+)	_	—	20	IIIA
	SM16		П			T2 (+) , Gate (−)	_	—	20	
	SM16	SM16J45A				T2 (−) , Gate (−)	_	—	20	
						T2 (-) , Gate (+)	_	—	—	
Peak On-State Voltage			V <sub>TM</sub>	I <sub>TM</sub> = 25A		_	—	1.5	V	
Gate Non-Trigger Voltage			$V_{GD}$	V <sub>D</sub> = Rated, Tc = 125°C		0.2	—	—	V	
Holding Current			Ι <sub>Η</sub>	V <sub>D</sub> = 12V, I <sub>TM</sub> = 2A		_	—	50	mA	
Critical Rate of Rise of Off-State Voltage at Commutation SM160		SM16G45 SM16J45		(dv / dt) c	V <sub>D</sub> = 400V, (di / dt) c = - 8.7A / ms T <sub>j</sub> = 125°C		10	_	_	V / µs
		SM16G45A SM16J45A		(uv / ul) C			4	_	_	
Thermal Resistance		R <sub>th (j−c)</sub>	Junction to Case, AC		_	_	1.4	°C/W		

## MARKING

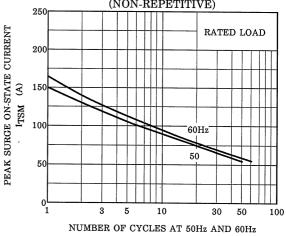


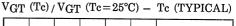
* NUMBER	SYMBOL		MARK	
* 1	TOSHIBA PRODUCT MARK		5	
* 2	TYPE	SM16G45, SM16G45A	M16G45	
		SM16J45, SM16J45A	M16J45	
* 3		SM16G45A, SM16J45A	А	
* 4	Lot Number		Example 8A: January 1998 8B: February 1998 8L: December 1998	

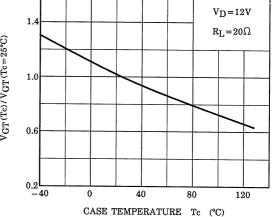


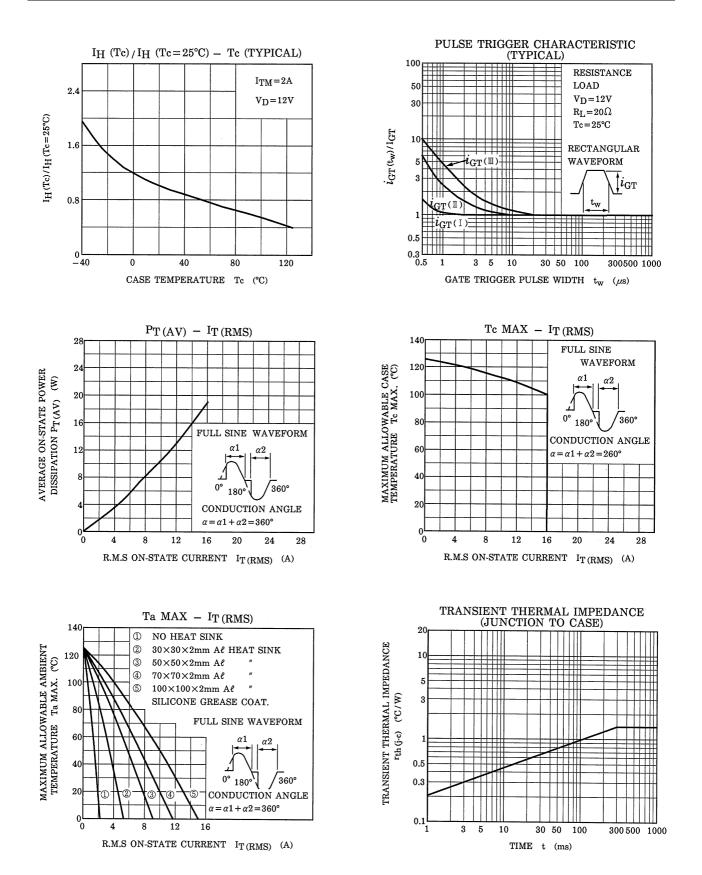












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